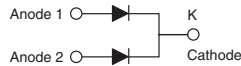
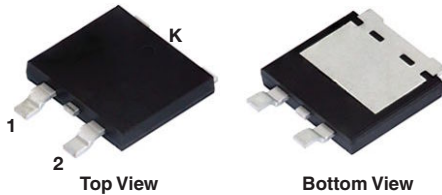


# Dual Low-Voltage TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier

 Ultra Low  $V_F = 0.36\text{ V}$  at  $I_F = 5.0\text{ A}$ 

## eSMP<sup>®</sup> Series SMPD (TO-263AC)



### DESIGN SUPPORT TOOLS AVAILABLE


[3D Models](#)

PRIMARY CHARACTERISTICS	
$I_{F(AV)}$	2 x 20 A
$V_{RRM}$	60 V
$I_{FSM}$	240 A
$V_F$ at $I_F = 20\text{ A}$ ( $T_A = 125\text{ °C}$ )	0.54 V
$T_J$ max.	175 °C
Package	SMPD (TO-263AC)
Circuit configuration	Common cathode

### FEATURES

- Trench MOS Schottky technology
- Very low profile - typical height of 1.7 mm
- Ideal for automated placement
- Low forward voltage drop, low power losses
- High efficiency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified available:
  - Automotive ordering code: base P/NHM3
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)

 AUTOMOTIVE  
GRADE  
Available

**RoHS**  
COMPLIANT  
HALOGEN  
**FREE**

### TYPICAL APPLICATIONS

For use in high frequency DC/DC converters, switching power supplies, freewheeling diodes, OR-ing diode, and reverse battery protection in commercial, industrial, and automotive application.

### MECHANICAL DATA

**Case:** SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating

Base P/N-M3 - halogen-free, RoHS-compliant

Base P/NHM3 - halogen-free, RoHS-compliant, and AEC-Q101 qualified

**Terminals:** matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 and HM3 suffix meet JESD 201 class 2 whisker test

**Polarity:** as marked

MAXIMUM RATINGS ( $T_A = 25\text{ °C}$ unless otherwise noted)			
PARAMETER	SYMBOL	V40DM60C	UNIT
Device marking code		V40DM60C	
Maximum repetitive peak reverse voltage	$V_{RRM}$	60	V
Maximum average forward rectified current (fig. 1)	per device	40	A
	per diode	20	
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	240	A
Operating junction temperature range	$T_J$ (2)	-40 to +175	°C
Storage temperature range	$T_{STG}$	-55 to +175	

### Notes

(1) Mounted on infinite heatsink

 (2) The heat generated must be less than the thermal conductivity from junction-to-ambient:  $dP_D/dT_J < 1/R_{\theta JA}$



ELECTRICAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 5 A	T <sub>A</sub> = 25 °C	V <sub>F</sub> <sup>(1)</sup>	0.47	-	V
	I <sub>F</sub> = 10 A			0.43	-	
	I <sub>F</sub> = 20 A			0.60	0.65	
	I <sub>F</sub> = 5 A	T <sub>A</sub> = 125 °C		0.36	-	
	I <sub>F</sub> = 10 A			0.52	-	
	I <sub>F</sub> = 20 A			0.54	0.62	
Reverse current at rated V <sub>R</sub> per diode	V <sub>R</sub> = 60 V	T <sub>A</sub> = 25 °C	I <sub>R</sub> <sup>(2)</sup>	-	1.5	mA
		T <sub>A</sub> = 125 °C		6.5	30	
Typical junction capacitance	4.0 V, 1 MHz		C <sub>J</sub>	2750	-	pF

**Notes**

- (1) Pulse test: 300 μs pulse width, 1 % duty cycle  
(2) Pulse test: Pulse width ≤ 5 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)			
PARAMETER	SYMBOL	V40DM60C	UNIT
Typical thermal resistance per device	R <sub>θJC</sub> <sup>(1)</sup>	1.0	°C/W
	R <sub>θJA</sub> <sup>(2)(3)</sup>	50	

**Notes**

- (1) Mounted on infinite heatsink  
(2) The heat generated must be less than the thermal conductivity from junction-to-ambient: dP<sub>D</sub>/dT<sub>J</sub> < 1/R<sub>θJA</sub> - junction-to-ambient  
(3) Free air, without heatsink

ORDERING INFORMATION (Example)				
PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE
V40DM60C-M3/I	0.55	I	2000/reel	13" diameter plastic tape and reel
V40DM60CHM3/I <sup>(1)</sup>	0.55	I	2000/reel	13" diameter plastic tape and reel

**Note**

- (1) AEC-Q101 qualified

**RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25\text{ }^\circ\text{C}$  unless otherwise noted)

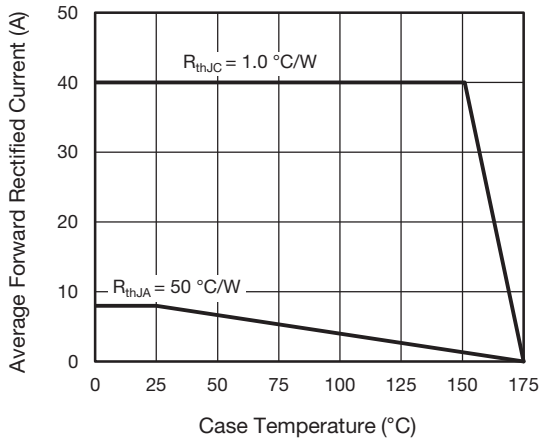


Fig. 1 - Maximum Forward Current Derating Curve

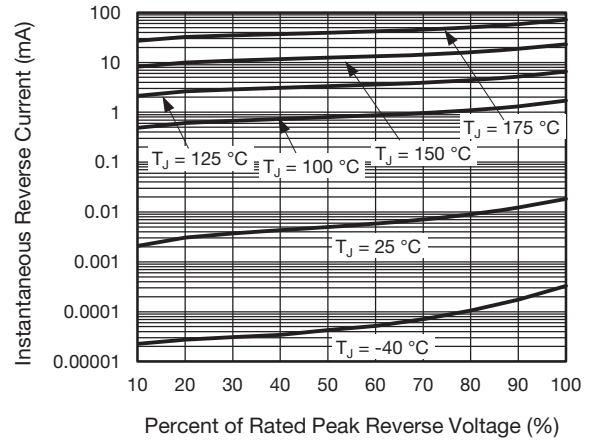


Fig. 4 - Typical Reverse Leakage Characteristics

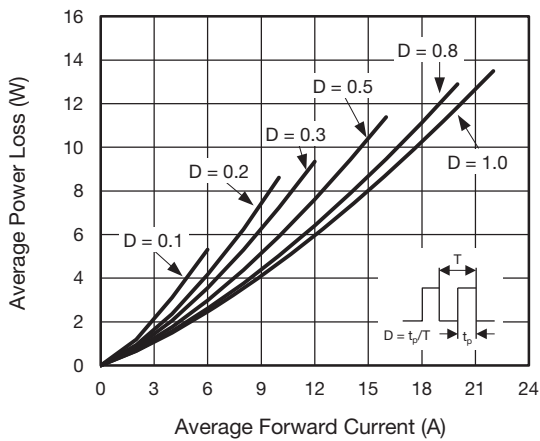


Fig. 2 - Average Power Loss Characteristics

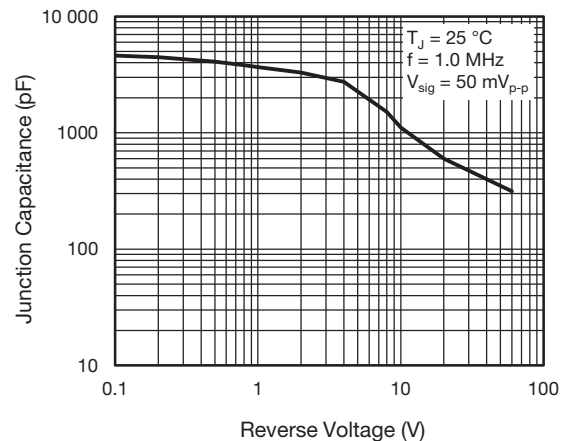


Fig. 5 - Typical Junction Capacitance

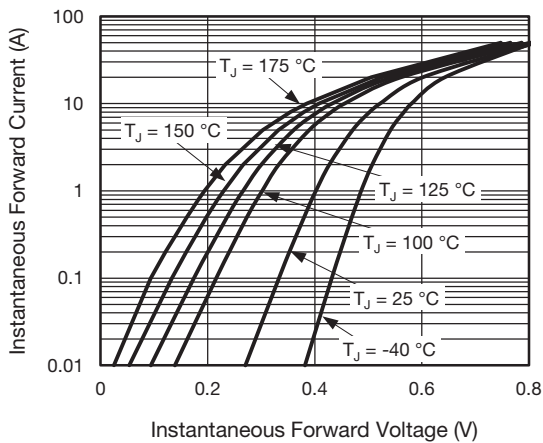


Fig. 3 - Typical Instantaneous Forward Characteristics

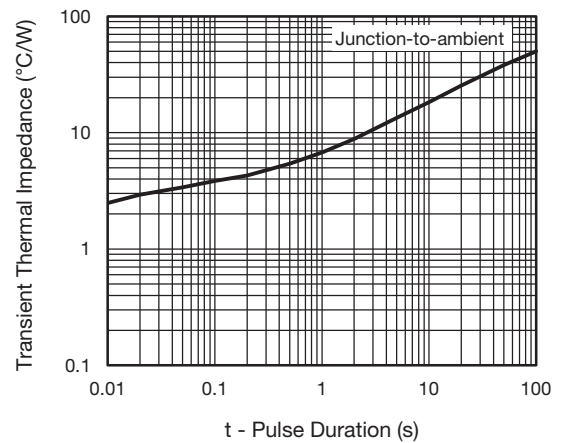


Fig. 6 - Typical Transient Thermal Impedance

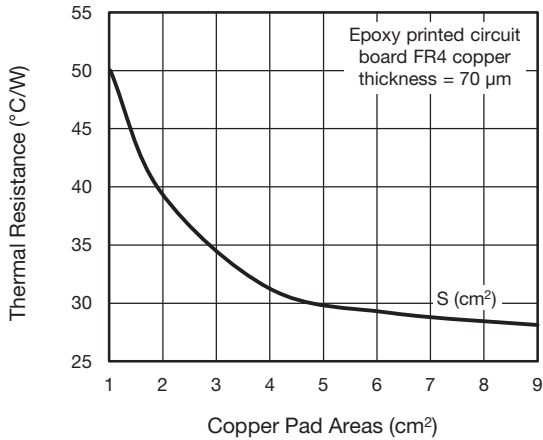
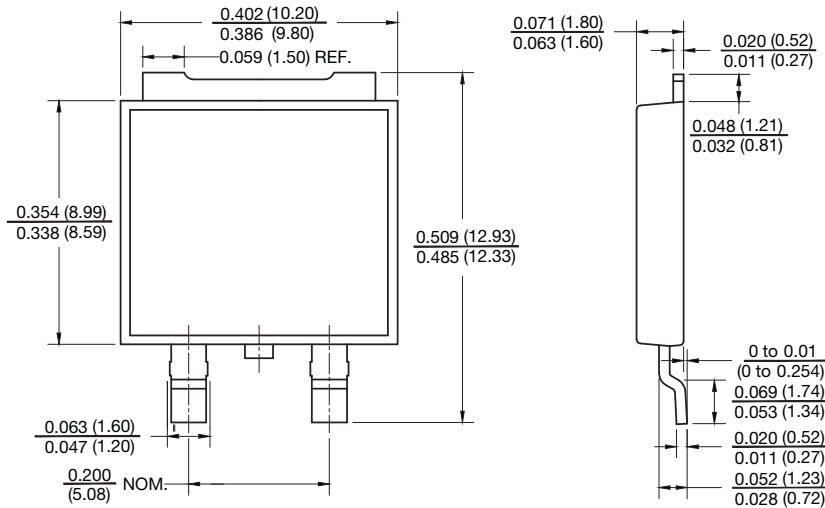


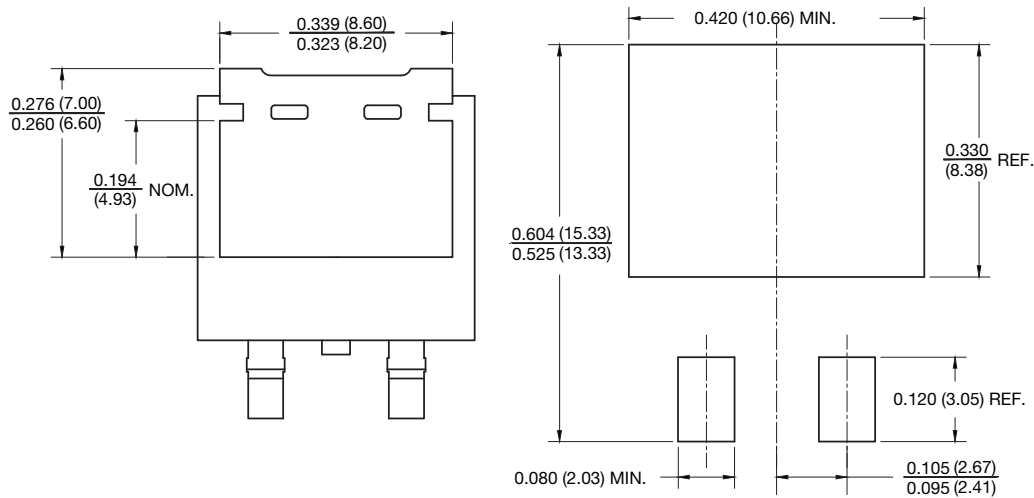
Fig. 7 - Thermal Resistance Junction-to-Ambient vs. Copper Pad Areas

**PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)

**SMPD (TO-263AC)**



**Mounting Pad Layout**





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